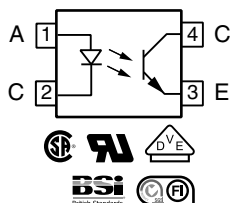
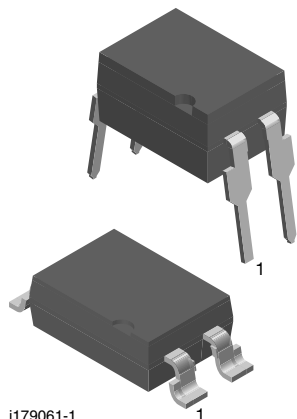




# Optocoupler, Phototransistor Output, Low Input Current



## FEATURES

- Good CTR linearity depending on forward current
- Low CTR degradation
- High collector emitter voltage,  $V_{CEO} = 55\text{ V}$
- Isolation test voltage,  $5300\text{ V}_{RMS}$
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode transient immunity
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



RoHS COMPLIANT

## APPLICATIONS

- Telecom
- Industrial controls
- Battery powered equipment
- Office machines

## AGENCY APPROVALS

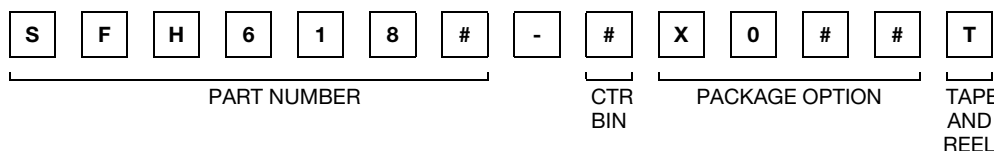
- UL1577, file no. E52744 system code H or J, double protection
- CSA 93751
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- BSI IEC 60950; IEC 60065
- FIMKO

## DESCRIPTION

The SFH618A (DIP) and SFH6186 (SMD) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 or SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits. The couplers are end-stackable with 2.54 mm lead spacing. Creepage and clearance distances of > 8 mm achieved with option 6.

## ORDERING INFORMATION



| AGENCY CERTIFIED/PACKAGE | CTR (%)                   |  |                           |   |
|--------------------------|---------------------------|--|---------------------------|---|
|                          | 1 mA                      |  |                           |   |
| <b>UL, CUL</b>           | <b>63 to 125</b>          | <b>100 to 200</b>  | <b>160 to 320</b>         | <b>250 to 500</b>   |
| DIP-4                    | SFH618A-2                 | SFH618A-3  | SFH618A-4                 | SFH618A-5   |
| DIP-4, 400 mil, option 6 | -                         | SFH618A-3X006  | -                         | -   |
| SMD-4, option 7          | -                         | -  | -                         | SFH618A-5X007T <sup>(1)</sup>                             |
| SMD-4, option 9          | SFH6186-2T <sup>(1)</sup> | SFH6186-3T <sup>(1)</sup> ,<br>SFH6186-3T1 <sup>(2)</sup> ,<br>SFH6186-3X002T <sup>(1)</sup> | SFH6186-4T <sup>(1)</sup> | SFH6186-5T <sup>(1)</sup> ,<br>SFH6186-5T1 <sup>(2)</sup> |
| <b>VDE, UL, CUL</b>      | <b>63 to 125</b>          | <b>100 to 200</b>  | <b>160 to 320</b>         | <b>250 to 500</b>   |
| DIP-4                    | -                         | SFH618A-3X001  | SFH618A-4X001             | -   |
| DIP-4, 400 mil, option 6 | -                         | SFH618A-3X016  | SFH618A-4X016             | SFH618A-5X016   |
| SMD-4, option 7          | -                         | SFH618A-3X017T <sup>(1)</sup>  | -                         | SFH618A-5X017T <sup>(1)</sup>                             |
| SMD-4, option 9          | -                         | SFH6186-3X001T <sup>(1)</sup>  | SFH6186-4X001T            | SFH6186-5X001T <sup>(1)</sup>                             |

## Notes

- Additional options may be possible, please contact sales office
- <sup>(1)</sup> Also available in tubes, do not put T to the end
- <sup>(2)</sup> Product is rotated 180° in tape and reel cavity



| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                   |                    |                  |
|---|---|-------------------|--------------------|------------------|
| PARAMETER   | TEST CONDITION  | SYMBOL            | VALUE              | UNIT             |
| <b>INPUT</b>  |   |                   |                    |                  |
| Reverse voltage   |   | V <sub>R</sub>    | 6                  | V                |
| Power dissipation   |   | P <sub>diss</sub> | 70                 | mW               |
| Forward current   |   | I <sub>F</sub>    | 60                 | mA               |
| <b>OUTPUT</b>   |   |                   |                    |                  |
| Collector emitter voltage   |   | V <sub>CEO</sub>  | 55                 | V                |
| Emitter collector voltage   |   | V <sub>ECO</sub>  | 7                  | V                |
| Collector current   |   | I <sub>C</sub>    | 50                 | mA               |
|   | t <sub>p</sub> ≤ 1 ms                                       | I <sub>C</sub>    | 100                | mA               |
| Power dissipation   |   | P <sub>diss</sub> | 150                | mW               |
| <b>COUPLER</b>  |   |                   |                    |                  |
| Isolation test voltage between emitter and detector                             | t = 1 s   | V <sub>ISO</sub>  | 5300               | V <sub>RMS</sub> |
| Isolation resistance  | V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C           | R <sub>IO</sub>   | ≥ 10 <sup>12</sup> | Ω                |
|   | V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C          | R <sub>IO</sub>   | ≥ 10 <sup>11</sup> | Ω                |
| Storage temperature range   |   | T <sub>stg</sub>  | - 55 to + 150      | °C               |
| Ambient temperature range   |   | T <sub>amb</sub>  | - 55 to + 100      | °C               |
| Junction temperature  |   | T <sub>j</sub>    | 125                | °C               |
| Soldering temperature <sup>(1)</sup>  | max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm | T <sub>slid</sub> | 260                | °C               |

**Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

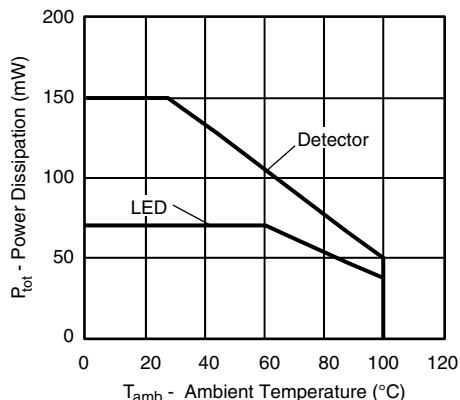


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature



| ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |           |                    |                |      |      |      |    |
|---|---|-----------|--------------------|----------------|------|------|------|----|
| PARAMETER   | TEST CONDITION                                  | PART      | SYMBOL             | MIN.           | TYP. | MAX. | UNIT |    |
| <b>INPUT</b>  |   |           |                    |                |      |      |      |    |
| Forward voltage   | I <sub>F</sub> = 5 mA                           |           | V <sub>F</sub>     |                | 1.1  | 1.5  | V    |    |
| Reverse current   | V <sub>R</sub> = 6 V                            |           | I <sub>R</sub>     |                | 0.01 | 10   | μA   |    |
| Capacitance   | V <sub>R</sub> = 0 V, f = 1 MHz                 |           | C <sub>O</sub>     |                | 25   |      | pF   |    |
| Thermal resistance  |   |           | R <sub>thja</sub>  |                | 1070 |      | K/W  |    |
| <b>OUTPUT</b>   |   |           |                    |                |      |      |      |    |
| Collector emitter leakage current   | V <sub>CE</sub> = 10 V                          |           | I <sub>CEO</sub>   |                | 10   | 200  | nA   |    |
| Collector emitter capacitance   | V <sub>CE</sub> = 5 V, f = 1 MHz                |           | C <sub>CE</sub>    |                | 7    |      | pF   |    |
| Thermal resistance  |   |           | R <sub>thja</sub>  |                | 500  |      | K/W  |    |
| <b>COUPLER</b>  |   |           |                    |                |      |      |      |    |
| Collector emitter saturation voltage  | I <sub>C</sub> = 0.32 mA, I <sub>F</sub> = 1 mA | SFH618A-2 | V <sub>CEsat</sub> |                | 0.25 | 0.4  | V    |    |
|   |   | SFH6186-2 | V <sub>CEsat</sub> |                | 0.25 | 0.4  | V    |    |
|   | I <sub>C</sub> = 0.5 mA, I <sub>F</sub> = 1 mA  | SFH618A-3 | V <sub>CEsat</sub> |                | 0.25 | 0.4  | V    |    |
|   |   | SFH6186-3 | V <sub>CEsat</sub> |                | 0.25 | 0.4  | V    |    |
|   | I <sub>C</sub> = 0.8 mA, I <sub>F</sub> = 1 mA  | SFH618A-4 | V <sub>CEsat</sub> |                | 0.25 | 0.4  | V    |    |
|   |   | SFH6186-4 | V <sub>CEsat</sub> |                | 0.25 | 0.4  | V    |    |
|   | I <sub>C</sub> = 1.25 mA, I <sub>F</sub> = 1 mA | SFH618A-5 | V <sub>CEsat</sub> |                | 0.25 | 0.4  | V    |    |
|   |   | SFH6186-5 | V <sub>CEsat</sub> |                | 0.25 | 0.4  | V    |    |
|   | Coupling capacitance                            |           |                    | C <sub>C</sub> |      | 0.25 |      | pF |

**Note**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

| CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |           |        |      |      |      |      |
|---|--|-----------|--------|------|------|------|------|
| PARAMETER   | TEST CONDITION                                   | PART      | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| I <sub>C</sub> /I <sub>F</sub>  | I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 0.5 V   | SFH618A-2 | CTR    | 63   |      | 125  | %    |
|   |  | SFH6186-2 | CTR    | 63   |      | 125  | %    |
|   | I <sub>F</sub> = 0.5 mA, V <sub>CE</sub> = 1.5 V | SFH618A-2 | CTR    | 32   | 75   |      | %    |
|   |  | SFH6186-2 | CTR    | 32   | 75   |      | %    |
|   | I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 0.5 V   | SFH618A-3 | CTR    | 100  |      | 200  | %    |
|   |  | SFH6186-3 | CTR    | 100  |      | 200  | %    |
|   | I <sub>F</sub> = 0.5 mA, V <sub>CE</sub> = 1.5 V | SFH618A-3 | CTR    | 50   | 120  |      | %    |
|   |  | SFH6186-3 | CTR    | 50   | 120  |      | %    |
|   | I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 0.5 V   | SFH618A-4 | CTR    | 160  |      | 320  | %    |
|   |  | SFH6186-4 | CTR    | 160  |      | 320  | %    |
|   | I <sub>F</sub> = 0.5 mA, V <sub>CE</sub> = 1.5 V | SFH618A-4 | CTR    | 80   | 200  |      | %    |
|   |  | SFH6186-4 | CTR    | 80   | 200  |      | %    |
|   | I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 0.5 V   | SFH618A-5 | CTR    | 250  |      | 500  | %    |
|   |  | SFH6186-5 | CTR    | 250  |      | 500  | %    |
|   | I <sub>F</sub> = 0.5 mA, V <sub>CE</sub> = 1.5 V | SFH618A-5 | CTR    | 125  | 300  |      | %    |
|   |  | SFH6186-5 | CTR    | 125  | 300  |      | %    |

| SWITCHING CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                  |      |      |      |      |  |
|--|--|------------------|------|------|------|------|--|
| PARAMETER  | TEST CONDITION   | SYMBOL           | MIN. | TYP. | MAX. | UNIT |  |
| Turn on time   | V <sub>CC</sub> = 5 V, I <sub>C</sub> = 2 mA, R <sub>L</sub> = 100 Ω | t <sub>on</sub>  |      | 6    |      | μs   |  |
| Rise time  | V <sub>CC</sub> = 5 V, I <sub>C</sub> = 2 mA, R <sub>L</sub> = 100 Ω | t <sub>r</sub>   |      | 3.5  |      | μs   |  |
| Turn off time  | V <sub>CC</sub> = 5 V, I <sub>C</sub> = 2 mA, R <sub>L</sub> = 100 Ω | t <sub>off</sub> |      | 5.5  |      | μs   |  |
| Fall time  | V <sub>CC</sub> = 5 V, I <sub>C</sub> = 2 mA, R <sub>L</sub> = 100 Ω | t <sub>f</sub>   |      | 5    |      | μs   |  |

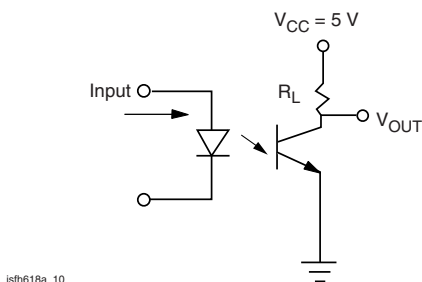


Fig. 2 - Test Circuit

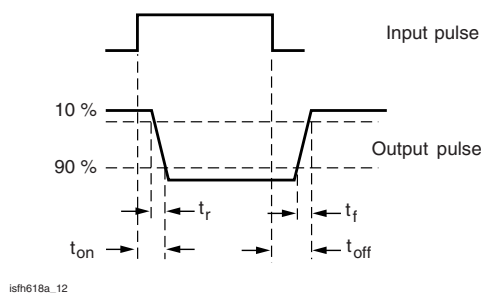


Fig. 3 - Test Circuit and Waveforms

| SAFETY AND INSULATION RATINGS                       |                       |        |       |           |      |      |
|---|-----------------------|--------|-------|-----------|------|------|
| PARAMETER   | TEST CONDITION        | SYMBOL | MIN.  | TYP.      | MAX. | UNIT |
| Climatic classification (according to IEC68 part 1) |                       |        |       | 55/100/21 |      |      |
| Comparative tracking index                          |                       | CTI    | 175   |           | 399  |      |
| $V_{IOTM}$  |                       |        | 10000 |           |      | V    |
| $V_{IORM}$  |                       |        | 890   |           |      | V    |
| $P_{SO}$  |                       |        |       |           | 400  | mW   |
| $I_{SI}$  |                       |        |       |           | 275  | mA   |
| $T_{SI}$  |                       |        |       |           | 175  | °C   |
| Creepage distance                                   | Standard DIP-4        |        | 7     |           |      | mm   |
| Clearance distance                                  | Standard DIP-4        |        | 7     |           |      | mm   |
| Creepage distance                                   | 400 mil DIP-4         |        | 8     |           |      | mm   |
| Clearance distance                                  | 400 mil DIP-4         |        | 8     |           |      | mm   |
| Insulation thickness, reinforced rated              | per IEC60950 2.10.5.1 |        | 0.4   |           |      | mm   |

**Note**

- As per IEC60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ °C}$ , unless otherwise specified)

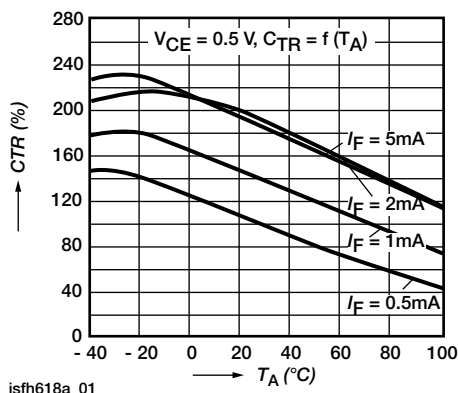


Fig. 4 - Current Transfer Ratio (typ.)

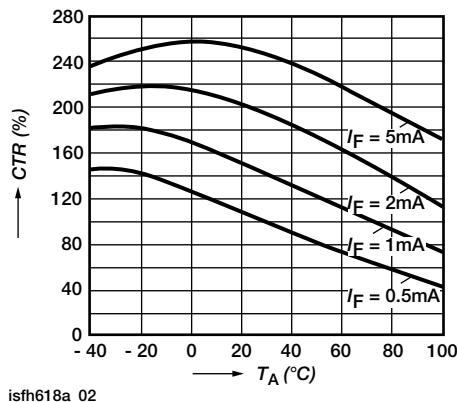


Fig. 5 - Current Transfer Ratio (typ.)

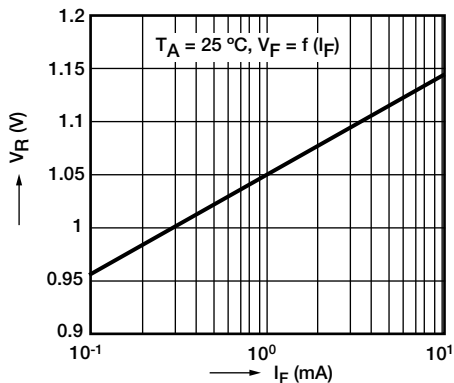


Fig. 6 - Diode Forward Voltage (typ.)

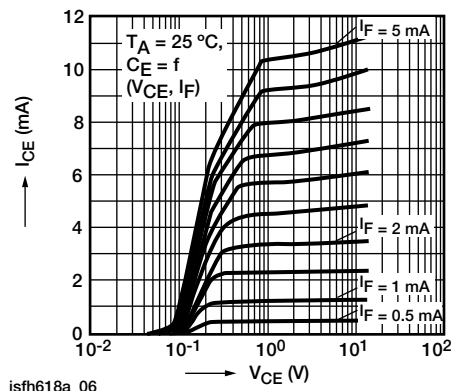


Fig. 9 - Output Characteristics

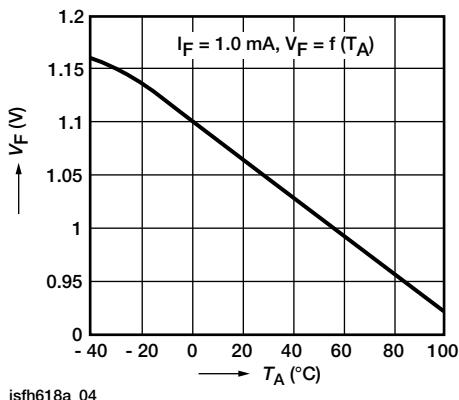


Fig. 7 - Diode Forward Voltage (typ.)

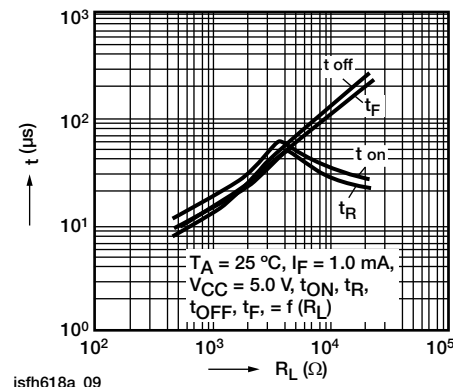


Fig. 10 - Switching Times (typ.)

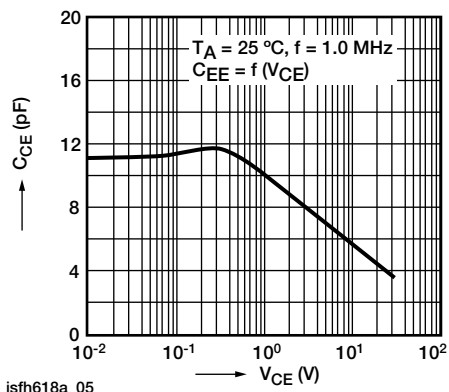
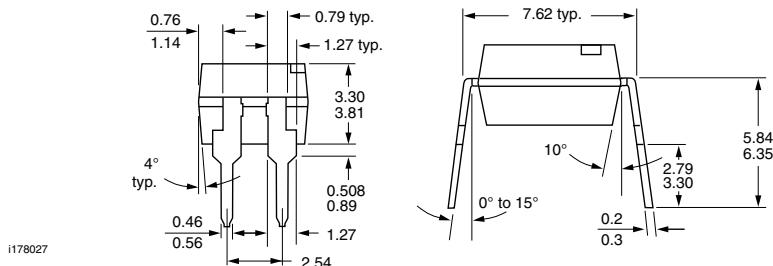
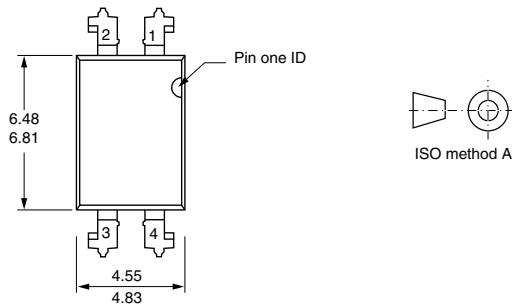


Fig. 8 - Transistor Capacitance

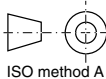
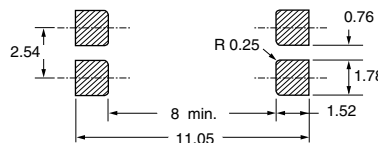
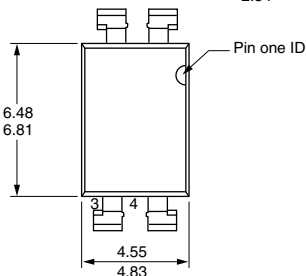


PACKAGE DIMENSIONS in millimeters

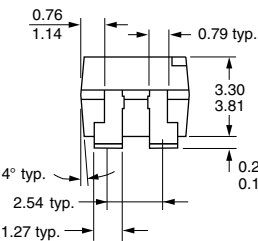


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SMD

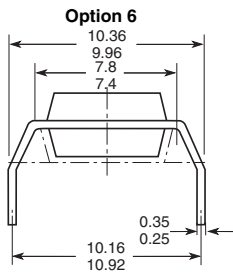
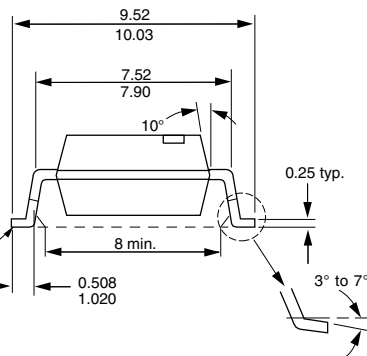


ISO method A

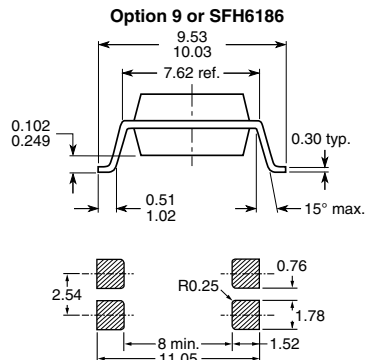
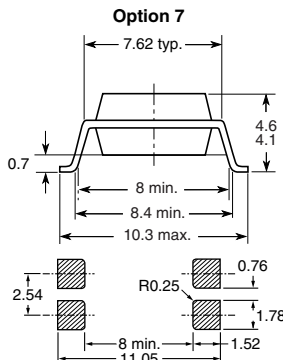


i178029

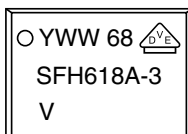
Lead coplanarity 0.004 max.



18450-11



PACKAGE MARKING





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**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

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<http://moschip.ru/get-element>

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